

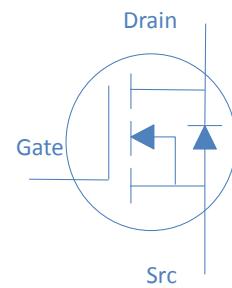
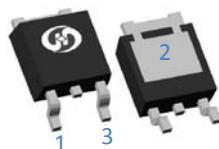
30V N-Ch Power MOSFET
Feature

- ◇ High Speed Power Switching, Logic Level
- ◇ Enhanced Avalanche Ruggedness
- ◇ 100% UIS Tested, 100% Rg Tested
- ◇ Lead Free, Halogen Free

V_{DS}	30	V
$R_{DS(on),typ}$ $V_{GS}=10V$	12	$m\Omega$
I_D (Silicon Limited)	25	A

Application

- ◇ Hard Switching and High Speed Circuit
- ◇ DC/DC in Telecoms and Industrial

TO-252


Part Number	Package	Marking
HTD140N03	TO-252	TD140N03

Absolute Maximum Ratings at $T_j=25^\circ C$ (unless otherwise specified)

Parameter	Symbol	Conditions	Value	Unit
Continuous Drain Current (Silicon Limited)	I_D	$T_C=25^\circ C$	25	A
		$T_C=100^\circ C$	20	
Drain to Source Voltage	V_{DS}	-	30	V
Gate to Source Voltage	V_{GS}	-	± 20	V
Pulsed Drain Current	I_{DM}	-	100	A
Avalanche Energy, Single Pulse	E_{AS}	$L=0.1mH, T_C=25^\circ C$	20	mJ
Power Dissipation	P_D	$T_C=25^\circ C$	43	W
Operating and Storage Temperature	T_J, T_{stg}	-	-55 to 175	°C

Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Ambient	$R_{\theta JA}$	62	°C/W
Thermal Resistance Junction-Case	$R_{\theta JC}$	3.5	°C/W

Electrical Characteristics at $T_j=25^\circ\text{C}$ (unless otherwise specified)
Static Characteristics

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_D=250\mu\text{A}$	30	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{GS}}=V_{\text{DS}}, I_D=250\mu\text{A}$	1	1.7	3	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=24\text{V}, T_j=25^\circ\text{C}$	-	-	1	μA
		$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=20\text{V}, T_j=125^\circ\text{C}$	-	-	25	
Gate to Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Drain to Source on Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_D=15\text{A}$	-	12	14	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_D=10\text{A}$	-	20	25	
Transconductance	g_{fs}	$V_{\text{DS}}=5\text{V}, I_D=15\text{A}$	-	15	-	S
Gate Resistance	R_G	$V_{\text{GS}}=15\text{mV}, V_{\text{DS}}=0\text{V}, f=1\text{MHz}$	-	2.0	-	Ω

Dynamic Characteristics

Input Capacitance	C_{iss}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=15\text{V}, f=1\text{MHz}$	-	597	-	pF
Output Capacitance	C_{oss}		-	111	-	
Reverse Transfer Capacitance	C_{rss}		-	96	-	
Total Gate Charge	$Q_g(10\text{V})$	$V_{\text{DD}}=15\text{V}, I_D=15\text{A}, V_{\text{GS}}=10\text{V}$	-	16	-	nC
	$Q_g(4.5\text{V})$		-	6	-	
Gate to Source Charge	Q_{gs}		-	1.8	-	
Gate to Drain (Miller) Charge	Q_{gd}		-	5.0	-	
Turn on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=15\text{V}, I_D=1\text{A}, V_{\text{GS}}=10\text{V}, R_G=2.7\Omega$	-	10	-	ns
Rise time	t_r		-	8	-	
Turn off Delay Time	$t_{\text{d}(\text{off})}$		-	20	-	
Fall Time	t_f		-	5	-	

Reverse Diode Characteristics

Diode Forward Voltage	V_{SD}	$V_{\text{GS}}=0\text{V}, I_F=25\text{A}$	-		1.3	V
Reverse Recovery Time	t_{rr}	$I_F=25\text{A}, dI_F/dt=100\text{A}/\mu\text{s}$	-	18	-	ns
Reverse Recovery Charge	Q_{rr}		-	10	-	nC

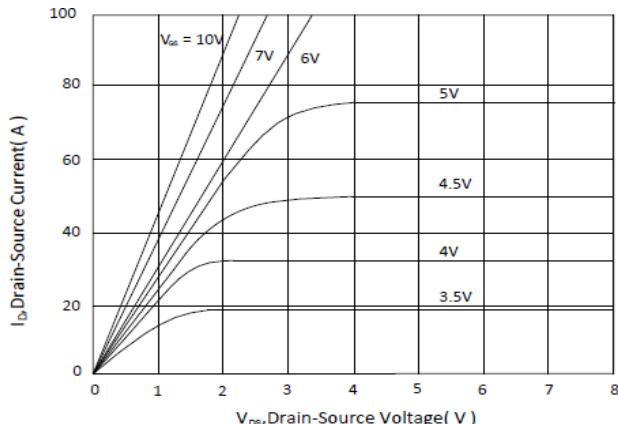
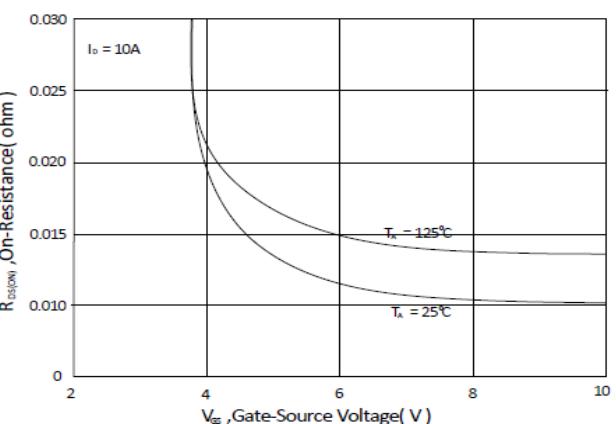
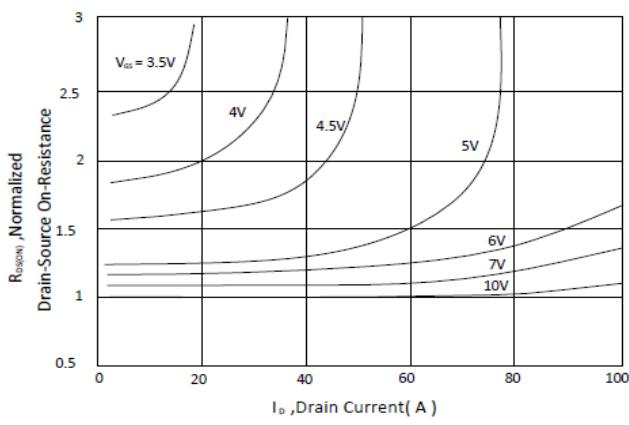
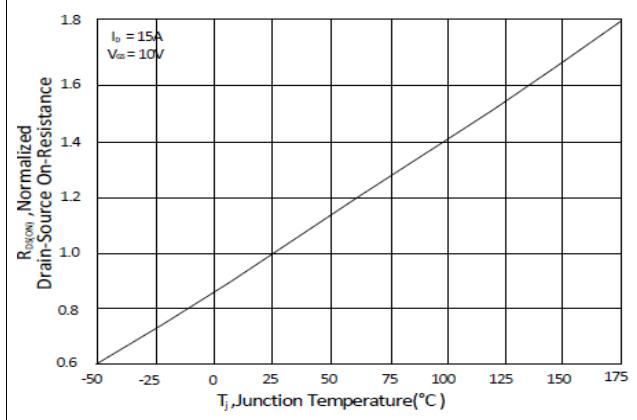
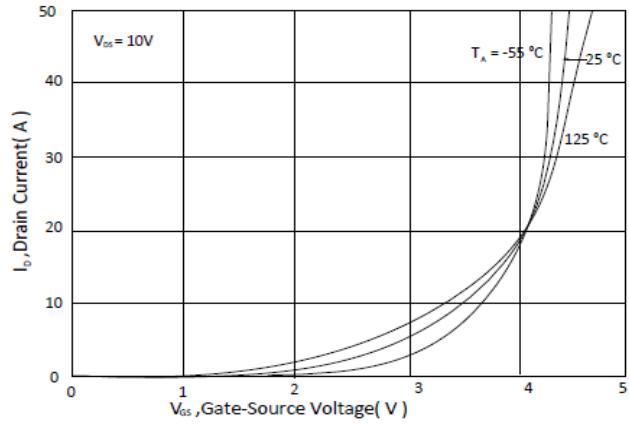
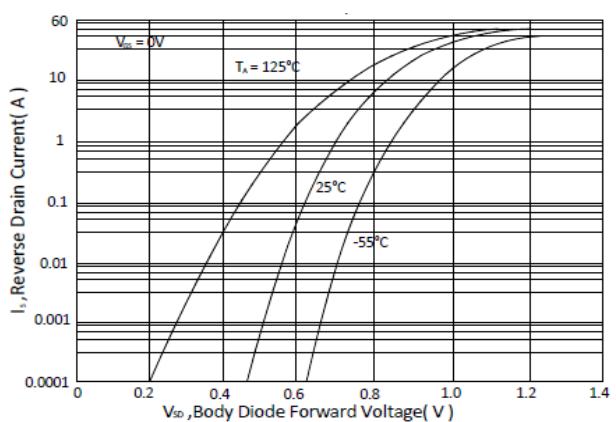
Fig 1. Typical Output Characteristics

Figure 2. On-Resistance vs. Gate-Source Voltage

Figure 3. On-Resistance vs. Drain Current and Gate Voltage

Figure 4. Normalized On-Resistance vs. Junction Temperature

Figure 5. Typical Transfer Characteristics

Figure 6. Typical Source-Drain Diode Forward Voltage


Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

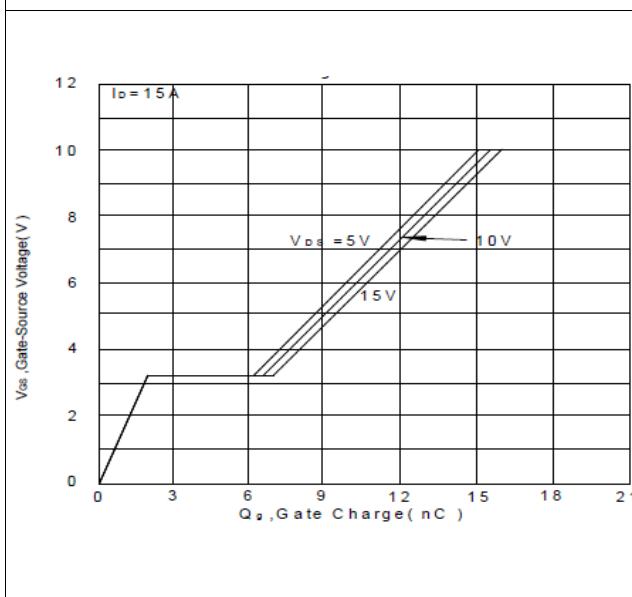


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

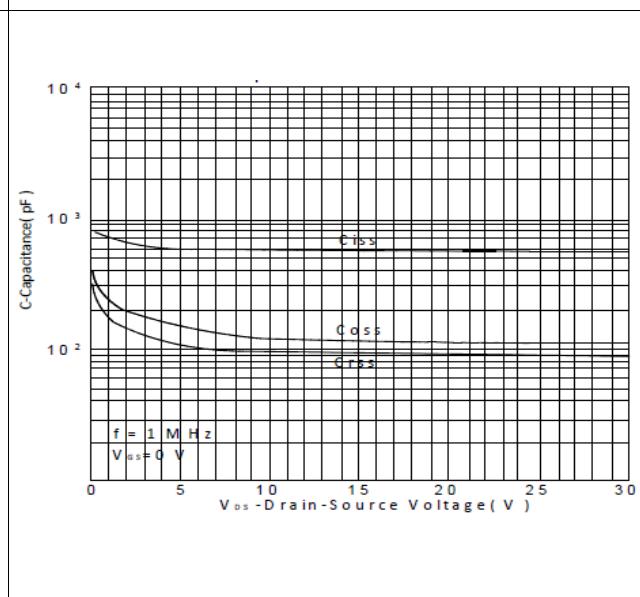


Figure 9. Maximum Safe Operating Area

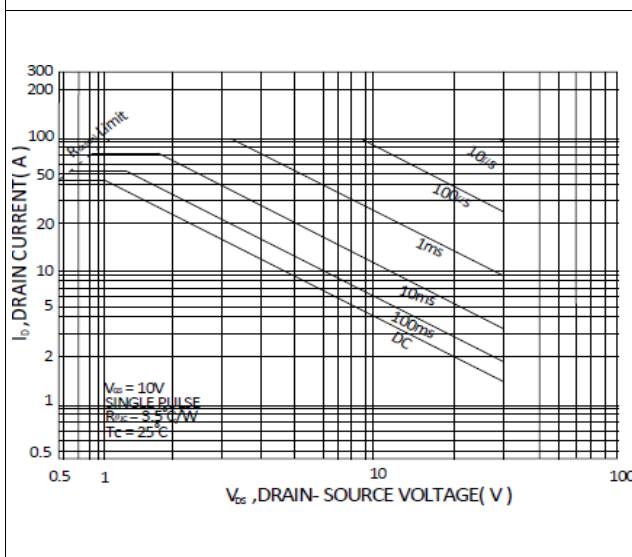


Figure 10. Single Pulse Maximum Power Dissipation

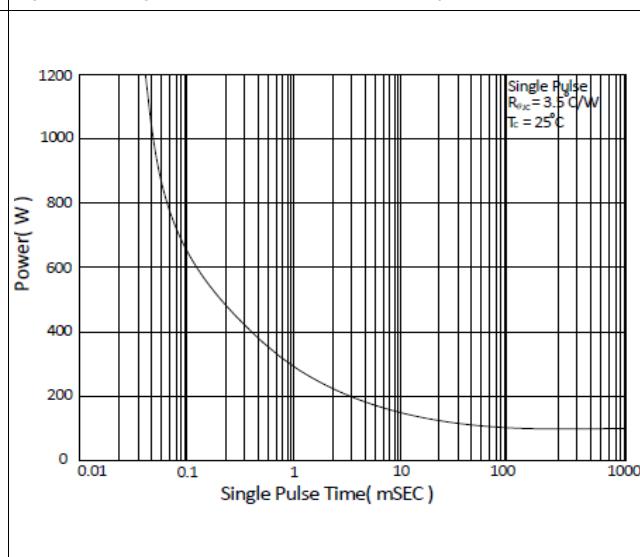
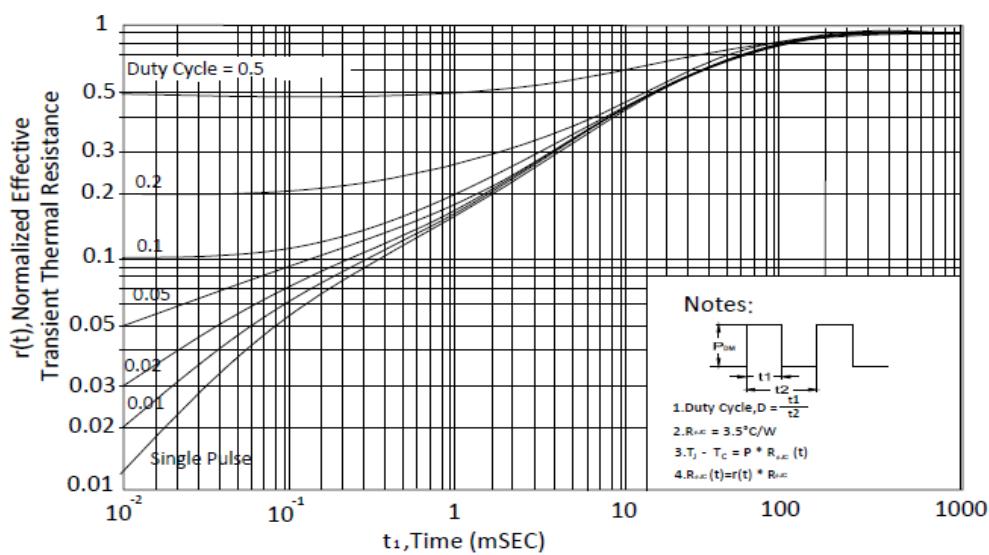
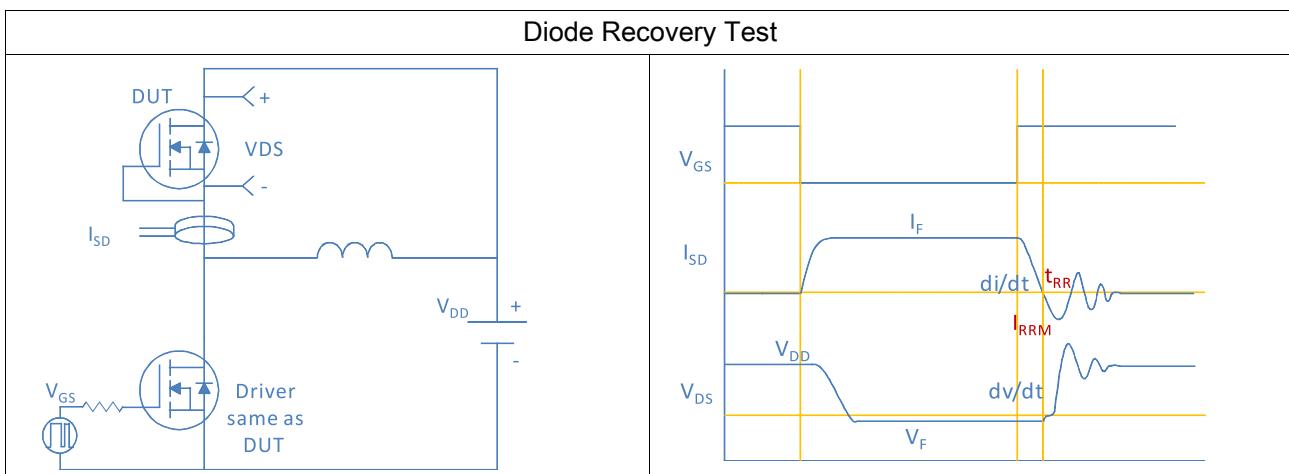
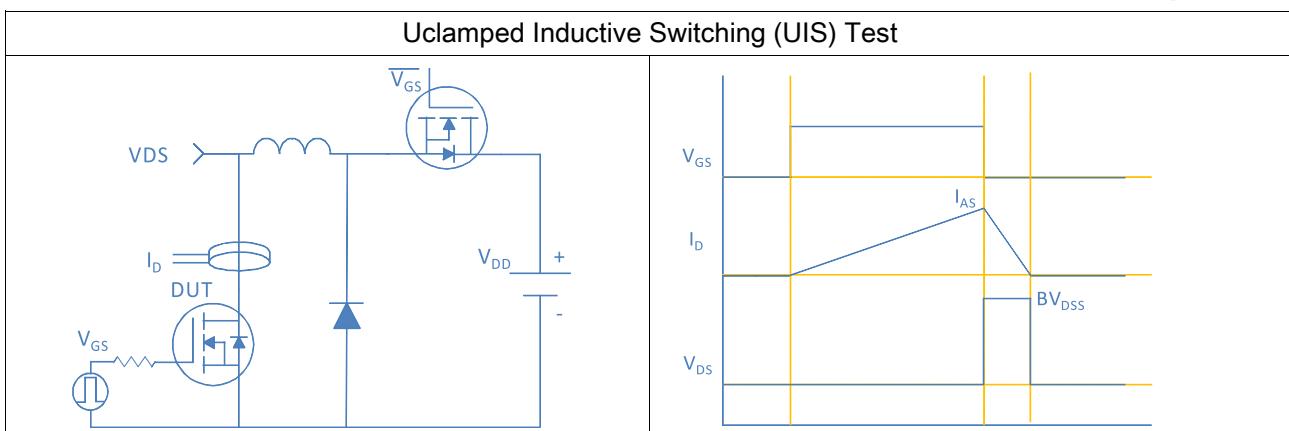
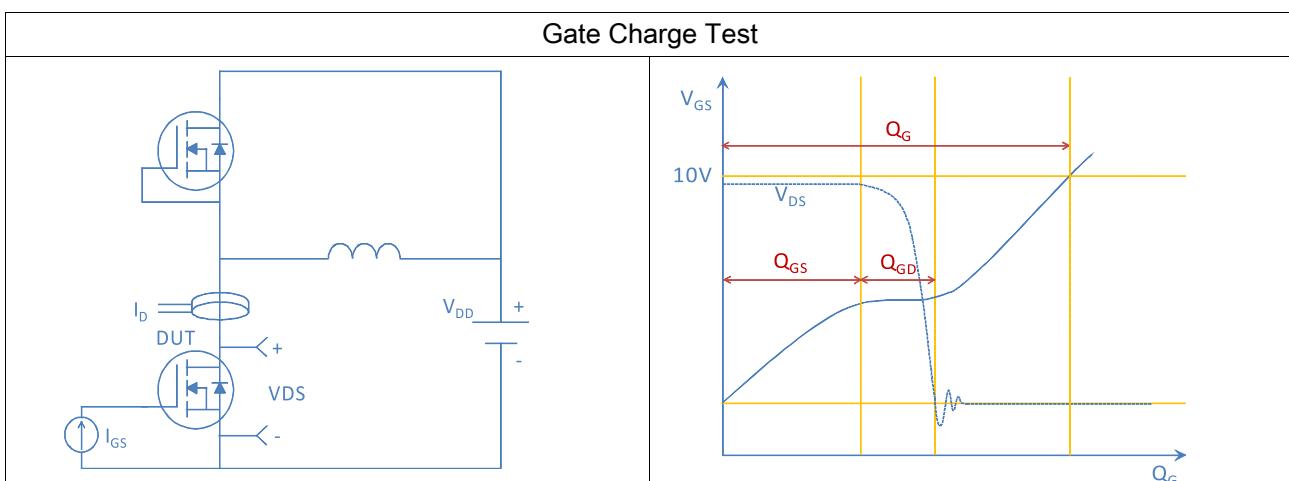
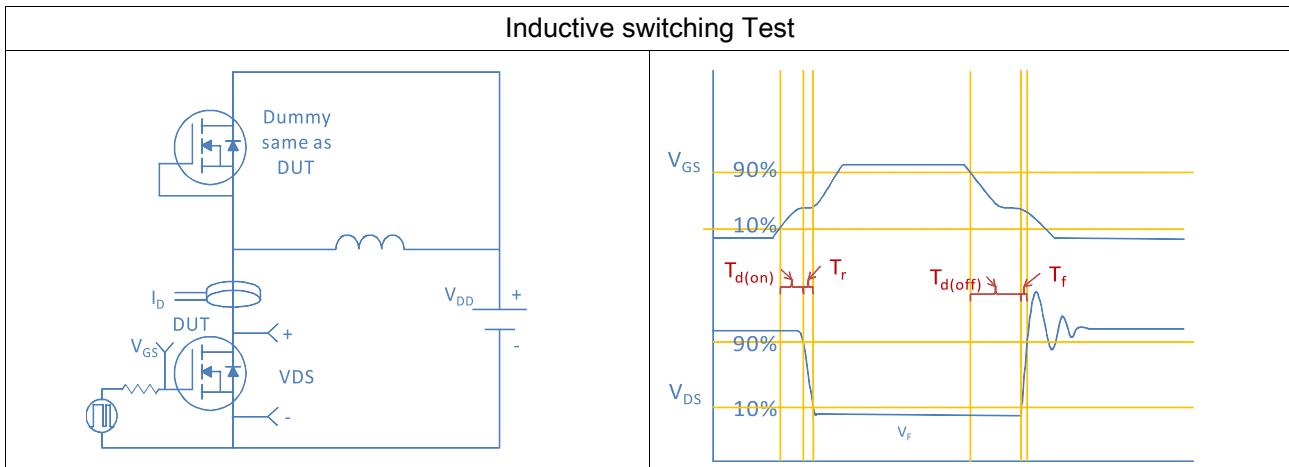
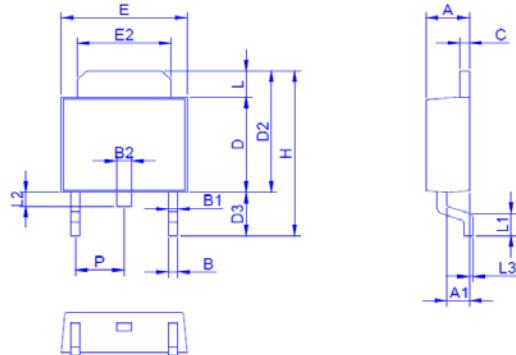


Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Ambient





Package Outline
TO-252, 2 leads

Dimension in mm

Dimension	A	A1	B	B1	B2	C	D	D2	D3	E	E2	H	L	L1	L2	L3	P
Min.	2.10	0.95	0.30	0.40	0.60	0.40	5.30	6.70	2.20	6.40	4.80	9.20	0.89	0.90	0.50	0.00	2.10
Max.	2.50	1.30	0.85	0.94	1.00	0.60	6.20	7.30	3.00	6.70	5.45	10.15	1.70	1.65	1.10	0.30	2.50